NSN 5961-00-051-2251

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View Online at https://aerobasegroup.com/nsn/5961-00-051-2251
Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
1.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.0 emitter to base voltage, dc and 2.0 dc, open-circuit voltage, floating potential, between the collector and base, with the emitter biased
in the reverse direction with respect to the base
Current Rating Per Characteristic:
750.00 milliamperes source cutoff current blank
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/263 government specification

Shelf Life:

N/a

Unit Of Measure:

NIO

Demilitarization:

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